8-Pin DIP High Speed Transistor Optocouplers

Single-Channel: 6N135M, 6N136M, HCPL4503M Dual-Channel: HCPL2530M, HCPL2531M

Description

The 6N135M, 6N136M, HCPL4503M, HCPL2530M, and HCPL2531M optocouplers consist of an AlGaAs LED optically coupled to a high speed photodetector transistor for each channel.

A separate connection for the bias of the photodiode improves the speed by several orders of magnitude over conventional phototransistor optocouplers by reducing the base-collector capacitance of the input transistor.

The HCPL4503M has no internal connection to the phototransistor base for improved noise immunity. An internal noise shield provides superior common mode rejection of up to $50,000 \text{ V/}\mu\text{s}$.

Features

- High Speed 1 MBit/s
- Dual-Channel: HCPL2530M, HCPL2531M
- CTR Guaranteed 0°C to 70°C
- No Base Connection for Improved Noise Immunity (HCPL4503M)
- Superior CMR of 15,000 V/µs Minimum (HCPL4503M)
- Safety and Regulatory Approvals
 - UL1577, 5,000 VAC_{RMS} for 1 Minute
 - ♦ DIN EN/IEC60747-5-5
- These are Pb-Free Devices

Applications

- Line Receivers
- Pulse Transformer Replacement
- Output Interface to CMOS-LSTTL-TTL
- Wide–Bandwidth Analog Coupling

Related Resources

- <u>https://www.onsemi.com/products/interfaces/high-performance-opto</u> <u>couplers</u>
- <u>https://www.onsemi.com/products/interfaces/high-performance-opto</u> couplers/high-performance-transistor-optocouplers/hcpl0500
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MARKING DIAGRAM



6N135 = Device Number

'53'

V

- = DIN EN/IEC60747-5-5 Option (only appears on component ordered with this option)
- XX = Two Digit Year Code, e.g., '15'
- YY = Two Digit Work Week Ranging from '01' to
- B = Assembly Package Code

ORDERING INFORMATION

See detailed ordering and shipping information on page 11 of this data sheet.



Figure 1. Schematics

SAFETY AND INSULATION RATINGS (As per DIN EN/IEC 60747–5–5, this optocoupler is suitable for "safe electrical insulation" only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits.)

Parameter	Characteristics	
Installation Classifications per DIN VDE 0110/1.89 Table 1, For Rated Mains Voltage	I–IV	
	I–IV	
	I–III	
	<600 V _{RMS}	I–III
Climatic Classification	40/100/21	
Pollution Degree (DIN VDE 0110/1.89)	2	
Comparative Tracking Index	175	

Symbol	Parameter	Value	Unit
V _{PR}	Input-to-Output Test Voltage, Method A, $V_{IORM} \times 1.6 = V_{PR}$, Type and Sample Test with t _m = 10 s, Partial Discharge < 5 pC	1,335	V _{peak}
	Input–to–Output Test Voltage, Method B, $V_{IORM} \times 1.875 = V_{PR}$, 100% Production Test with $t_m = 1 s$, Partial Discharge < 5 pC	1,669	V _{peak}
VIORM	Maximum Working Insulation Voltage	890	V _{peak}
V _{IOTM}	Highest Allowable Over-Voltage	6,000	V _{peak}
	External Creepage	≥8.0	mm
	External Clearance	≥7.4	mm
	External Clearance (for Option TV, 0.4" Lead Spacing)	≥10.16	mm
DTI	Distance Through Insulation (Insulation Thickness)	≥0.5	mm
Τ _S	Case Temperature (Note 1)	150	°C
I _{S,INPUT}	Input Current (Note 1)	200	mA
P _{S,OUTPUT}	Output Power (Duty Factor \leq 2.7%) (Note 1)	300	mW
R _{IO}	Insulation Resistance at T _S , V _{IO} = 500 V (Note 1)	>10 ⁹	Ω

1. Safety limit value - maximum values allowed in the event of a failure.

Symbol	Parameter	Test Conditions	Value	Unit
T _{STG}	Storage Temperature		-40 to +125	°C
T _{OPR}	Operating Temperature		-40 to +100	°C
Т _Ј	Junction Temperature		-40 to +125	°C
T _{SOL}	Lead Solder Temperature		260 for 10 s	°C
EMITTER				

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

I _F (avg)	DC/Average Forward Input Current Each Channel (Note 2)		25	mA
I _F (pk)	Peak Forward Input Current Each Channel (Note 3)	50% Duty Cycle, 1 ms P.W.	50	mA
I _F (trans)	Peak Transient Input Current Each Channel	≤1 μs P.W., 300 pps	1.0	А
V _R	Reverse Input Voltage Each Channel		5	V
PD	Input Power Dissipation Each Channel (Note 4)		45	mW

DETECTOR

I _O (avg)	Average Output Current Each Channel		8	mA
l _O (pk)	Peak Output Current Each Channel		16	mA
V _{EBR}	Emitter-Base Reverse Voltage	6N135M and 6N136M	5	V
V _{CC}	Supply Voltage		-0.5 to 30	V
V _O	Output Voltage		-0.5 to 20	V
۱ _B	Base Current	6N135M and 6N136M	5	mA
PD	Output Power Dissipation Each Channel (Note 5)		100	mW

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

2. Derate linearly above 70°C free-air temperature at a rate of 0.8 mA/°C.

3. Derate linearly above 70°C free-air temperature at a rate of 1.6 mA/°C.

4. Derate linearly above 70°C free-air temperature at a rate of 0.9 mW/°C.

5. Derate linearly above 70°C free-air temperature at a rate of 2.0 mW/°C.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Мах	Unit
V _{CC}	Supply Voltage	4.5	20.0	V
T _A	Ambient Operating Temperature	0	70	°C
I _{FL}	Input Current, Low Level	0	250	μA
I _{FH}	Input Current, High Level (Note 6)	6.3	20.0	mA

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

6. 6.3 mA is a guard banded value which allows for at least 20% CTR degradation. Initial input current threshold value is 5.0 mA or less.

ELECTRICAL CHARACTERISTICS								
Symbol	Parameter	Device	Test Conditions	Min	Тур	Max	Unit	
INDIVIDUA	L COMPONENT CHARAC	TERISTICS (V _{CC}	$_{\rm C}$ = 5.0 V, T _A = 0°C to 70°C unless otherwise	e specified	d.)			
EMITTER								
V _F	Input Forward Voltage	All	$I_{F} = 16 \text{ mA}, T_{A} = 25^{\circ}\text{C}$	-	1.45	1.70	V	
		All	I _F = 16 mA	-	-	1.80		
B _{VR}	Input Reverse Breakdown Voltage	All	I _R = 10 μA	5	21	_	V	
$\Delta V_F / \Delta T_A$	Temperature Coefficient of Forward Voltage	All	I _F = 16 mA	-	-1.7	-	mV/°C	
DETECTO	R							
	Logic High Output	All	I_F = 0 mA, V_O = V_{CC} = 5.5 V, T_A = 25°C	1	0.0007	0.5	μΑ	
I _{ОН}	Current	6N135M, 6N136M, HCPL4503M	$I_F = 0 \text{ mA}, V_O = V_{CC} = 15 \text{ V}, T_A = 25^{\circ}\text{C}$	_	0.0019	1		
		All	$I_F = 0 \text{ mA}, V_O = V_{CC} = 15 \text{ V}$	-	-	50		
	Logic Low Supply Current	6N135M, 6N136M, HCPL4503M	I_F = 16 mA, V_O = Open, V_{CC} = 15 V	-	163	200	μΑ	
002		HCPL2530M, HCPL2531M	I_{F1} = I_{F2} = 16 mA, V_O = Open, V_{CC} = 15 V	-	-	400		
I _{CCH}	Logic High Supply Current	6N135M, 6N136M, HCPL4503M	$I_F = 0 \text{ mA}, V_O = \text{Open}, V_{CC} = 15 \text{ V}$	-	0.0004	2	μΑ	
		HCPL2530M, HCPL2531M	$I_F = 0 \text{ mA}, V_O = \text{Open}, V_{CC} = 15 \text{ V}$	_	-	4		
TRANSFE	TRANSFER CHARACTERISTICS (T _A = 0°C to 70°C unless otherwise specified.)							

COUPLED								
CTR	Current Transfer Ratio (Note 7)	6N135M, HCPL2530M	$ I_F = 16 \text{ mA}, \text{V}_O = 0.4 \text{ V}, \text{V}_{CC} = 4.5 \text{ V}, \\ \text{T}_A = 25^{\circ}\text{C} $		7	38	50	%
		6N136M, HCPL4503M, HCPL2531M			19	38	50	%
		6N135M	I_F = 16 mA, V_{CC} = 4.5 V	V _{OL} = 0.4 V	5	-	-	%
		HCPL2530M		V _{OL} = 0.5 V				
		6N136M, HCPL4503M		V _{OL} = 0.4 V	15	-	-	%
		HCPL2531M		V _{OL} = 0.5 V				
V _{OL}	Logic LOW Output	6N135M			-	0.12	0.4	V
	voltage	HCPL2530M					0.5	
		6N136M, HCPL4503M			-	0.20	0.4	
		HCPL2531M					0.5	
		6N135M, HCPL2530M	I _F = 16 mA, I _O = 0.8 mA, V	/ _{CC} = 4.5 V	_	0.11	0.5	
		HCPL4503M, HCPL2531M	I _F = 16 mA, I _O = 2.4 mA, V	/ _{CC} = 4.5 V	-	0.18	0.5	

Symbol	Parameter	Device	Test Conditions	Min	Тур	Max	Unit
SWITCHING CHARACTERISTICS (T _A = 0° C to 70° C unless otherwise specified.)							
t _{PHL}	Propagation Delay Time	6N135M	$T_A = 25^{\circ}C$, $R_L = 4.1 \text{ k}\Omega$, $I_F = 16 \text{ mA}$	-	0.23	1.5	μs
	to Logic LOW	HCPL2530M	(Note 8) (Figure 14)		0.25		
		6N136M, HCPL4503M	T_A = 25°C, R_L = 1.9 kΩ, I_F = 16 mA (Note 9) (Figure 14)	-	0.25	0.8	μs
		HCPL2531M			0.28		
		6N135M, HCPL2530M	R_L = 4.1 kΩ, I_F = 16 mA (Note 8) (Figure 14)	-	-	2.0	μs
		6N136M, HCPL4503M, HCPL2531M	R_L = 1.9 kΩ, I_F = 16 mA (Note 9) (Figure 14)	-	-	1.0	μs
t _{PLH}	Propagation Delay Time	6N135M	$T_A = 25^{\circ}C, R_L = 4.1 \text{ k}\Omega, I_F = 16 \text{ mA}$	-	0.45	1.5	μs
	to Logic HIGH	HCPL2530M	M (Note 8) (Figure 14)		0.29		
		6N136M, HCPL4503M	$T_A = 25^{\circ}C, R_L = 1.9 k\Omega, I_F = 16 mA$ (Note 9) (Figure 14)	-	0.26	0.8	μs
		HCPL2531M			0.18		
		6N135M, HCPL2530M	R_L = 4.1 kΩ, I_F = 16 mA (Note 8) (Figure 14)	-	-	2.0	μs
		6N136M, HCPL4503M, HCPL2531M	R_L = 1.9 kΩ, I _F = 16 mA (Note 9) (Figure 14)	-	-	1.0	μs
CM _H	Common Mode Transient Immunity	6N135M, HCPL2530M	$ I_F = 0 \text{ mA}, V_{CM} = 10 \text{ V}_{P-P}, R_L = 4.1 \text{ k}\Omega, \\ T_A = 25^\circ C \text{ (Note 10) (Figure 15)} $	-	10,000	-	V/µs
	at Logic High	6N136M, HCPL2531M	$ I_F = 0 \text{ mA}, V_{CM} = 10 \text{ V}_{P-P} \text{ R}_L = 1.9 \text{ k}\Omega, \\ T_A = 25^{\circ}\text{C} \text{ (Note 10) (Figure 15)} $	-	10,000	-	
		HCPL4503M	I _F = 0 mA, V _{CM} = 1,500 V _{P-P} , R _L = 4.1 kΩ, T _A = 25°C (Note 10) (Figure 15)	15,000	50,000	-	
CM _L	Common Mode Transient Immunity	6N135M, HCPL2530M	I _F = 16 mA, V _{CM} = 10 V _{P-P} , R _L = 4.1 kΩ, T _A = 25°C (Note 10) (Figure 16)	-	10,000	-	V/μs
	ai Logic Low	6N136M, HCPL2531M	I _F = 16 mA, V _{CM} = 10 V _{P-P} , R _L = 1.9 kΩ (Note 10) (Figure 15)	-	10,000	_	
		HCPL4503M	I_F = 16 mA, V _{CM} = 1,500 V _{P-P} , R _L = 4.1 kΩ, T _A = 25°C (Note 10) (Figure 15)	15,000	50,000	_	

ELECTRICAL CHARACTERISTICS (continued)

Symbol	Parameter	Device	Test Conditions	Min	Тур	Max	Unit
ISOLATIO	N CHARACTERISTICS (T _f	$_{\rm A}$ = 25°C, unless	otherwise noted.)				
V _{ISO}	Withstand Isolation Test Voltage	All	$\begin{array}{l} RH \leq 50\%, \ I_{I-O} \leq 10 \ \mu A \\ t = 1 \ minute, \\ f = 50 \ Hz \ (Note \ 11) \ (Note \ 13) \end{array}$	5,000	-	-	VAC _{RMS}
R _{I-O}	Resistance (Input to Output)	All	V _{I-O} = 500 V _{DC} (Note 11)	-	10 ¹¹	_	Ω
C _{I-O}	Capacitance (Input to Output)	All	f = 1 MHz, V_{I-O} = 0 V_{DC} (Note 11)	-	1	-	pF
I _{I-I}	Input-Input Insulation Leakage Current	HCPL2530M, HCPL2531M	$\label{eq:hole} \begin{array}{l} RH \leq 45\%, \ V_{I-I} = 500 \ V_{DC}, \ t = 5 \ s \\ \mbox{(Note 12)} \end{array}$	-	<1	-	nA
R _{I-I}	Input-Input Resistance	HCPL2530M, HCPL2531M	V _{I-I} = 500 V _{DC} (Note 12)	_	10 ¹²	_	Ω
C _{I-I}	Input-Input Capacitance	HCPL2530M, HCPL2531M	f = 1 MHz (Note 12)	-	0.2	_	pF

ELECTRICAL CHARACTERISTICS (continued)

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

7. Current Transfer Ratio is defined as a ratio of output collector current, IO, to the forward LED input current, IF, times 100%.

8. The 4.1 k Ω load represents 1 LSTTL unit load of 0.36 mA and 6.1 k Ω pull-up resistor.

9. The 1.9 k Ω load represents 1 TTL unit load of 1.6 mA and 5.6 k Ω pull-up resistor.

10. Common mode transient immunity in logic high level is the maximum tolerable (positive) dV_{cm}/dt on the leading edge of the common mode

pulse signal, V_{CM} , to assure that the output will remain in a logic high state (i.e., $V_O > 2.0$ V). Common mode transient immunity in logic low level is the maximum tolerable (negative) dV_{cm}/dt on the trailing edge of the common mode pulse signal, V_{CM} , to assure that the output will remain in a logic low state (i.e., $V_O > 0.8$ V).

11. Device is considered a two terminal device: pins 1, 2, 3 and 4 are shorted together and pins 5, 6, 7 and 8 are shorted together.

12. Measured between pins 1 and 2 shorted together, and pins 3 and 4 shorted together.

13.5000 V_{RMS} for 1 minute duration is equivalent to 6000 V_{RMS} for 1 second duration.

TYPICAL PERFORMANCE CURVES

(For single-channel devices; 6N135M, 6N136M, and HCPL4503M.)







Figure 3. Normalized CTR vs. Temperature



Figure 4. Output Current vs. Output Voltage



Figure 6. Propagation Delay vs. Temperature



Figure 5. Logic High Output Current vs. Temperature



Figure 7. Propagation Delay vs. Load Resistance

TYPICAL PERFORMANCE CURVES

(For dual-channel devices; HCPL2530M and HCPL2531M.)







Figure 9. Normalized CTR vs. Temperature



Figure 10. Output Current vs. Output Voltage



Figure 12. Propagation Delay vs. Temperature



Figure 11. Logic High Output Current vs. Temperature



Figure 13. Propagation Delay vs. Load Resistance



Test Circuit for 6N135M, 6N136M, and HCPL4503M











Test Circuit for 6N135M, 6N136M, and HCPL4503M



Test Circuit for HCPL2530M and HCPL2531M



Figure 15. Common Mode Immunity Test Circuit



Profile Freature	Pb-Free Assembly Profile
Temperature Min. (Tsmin)	150°C
Temperature Max. (Tsmax)	200°C
Time (t _S) from (Tsmin to Tsmax)	60 to 120 s
Ramp-up Rate (t _L to t _P)	3°C/second maximum
Liquidous Temperature (TL)	217°C
Time (t_L) Maintained Above (T_L)	60 to 150 s
Peak Body Package Temperature	260°C +0°C / –5°C
Time (t _P) within 5°C of 260°C	30 s
Ramp-down Rate (T _P to T _L)	6°C/s maximum
Time 25°C to Peak Temperature	8 minutes maximum

Figure 16. Reflow Profile

ORDERING INFORMATION

Part Number	Package	Shipping [†]
6N135M	PDIP8 9.655x6.61, 2.54P DIP 8–Pin	50 Units / Tube
6N135SM	PDIP8 GW SMT 8-Pin (Lead Bend)	50 Units / Tube
6N135SDM	PDIP8 GW SMT 8-Pin (Lead Bend)	1,000 / Tape and Reel
6N135VM	PDIP8 9.655x6.61, 2.54P DIP 8–Pin, DIN IEC60747–5–5 Option	50 Units / Tube
6N135SVM	PDIP8 GW SMT 8-Pin (Lead Bend), DIN EN/IEC 60747-5-5 Option	50 Units / Tube
6N135SDVM	PDIP8 GW SMT 8-Pin (Lead Bend), DIN EN/IEC 60747-5-5 Option	1,000 / Tape and Reel
6N135TVM	PDIP8 6.6x3.81, 2.54P DIP 8-Pin, 0.4" Lead Spacing, DIN EN/IEC 60747-5-5 Option	50 Units / Tube
6N135TSVM	PDIP8 GW SMT 8-Pin, 0.4" Lead Spacing, DIN EN/IEC 60747-5-5 Option	50 Units / Tube
6N135TSR2VM	PDIP8 GW SMT 8-Pin, 0.4" Lead Spacing, DIN EN/IEC 60747-5-2 Option	1,000 / Tape and Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

NOTE: The product orderable part number system listed in this table also applies to the 6N136M, HCPL4503M, HCPL2530M and HCPL2531M product families.



PDIP8 6.6x3.81, 2.54P CASE 646BW ISSUE O

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